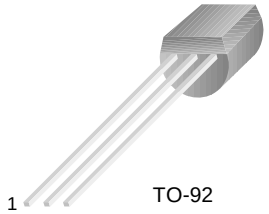
FAIRCHILD
SEMICONDUCTOR®

BC546/547/548/549/550

Switching and Applications

- High Voltage: BC546, V_{CEO}=65V
- Low Noise: BC549, BC550
- Complement to BC556 ... BC560



TO-92

1. Collector 2. Base 3. Emitter

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage : BC546	80	V
	: BC547/550	50	V
	: BC548/549	30	V
V_{CEO}	Collector-Emitter Voltage : BC546	65	V
	: BC547/550	45	V
	: BC548/549	30	V
V_{EBO}	Emitter-Base Voltage : BC546/547	6	V
	: BC548/549/550	5	V
I_C	Collector Current (DC)	100	mA
P_C	Collector Power Dissipation	500	mW
T_J	Junction Temperature	150	°C
T_{STG}	Storage Temperature	-65 ~ 150	°C

Electrical Characteristics T_a=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
I_{CBO}	Collector Cut-off Current	V_{CB}=30V, I_E=0			15	nA
h_{FE}	DC Current Gain	V_{CE}=5V, I_C=2mA	110		800	
V_{CE} (sat)	Collector-Emitter Saturation Voltage	I_C=10mA, I_B=0.5mA		90	250	mV
		I_C=100mA, I_B=5mA		200	600	mV
V_{BE} (sat)	Base-Emitter Saturation Voltage	I_C=10mA, I_B=0.5mA		700		mV
		I_C=100mA, I_B=5mA		900		mV
V_{BE} (on)	Base-Emitter On Voltage	V_{CE}=5V, I_C=2mA	580	660	700	mV
		V_{CE}=5V, I_C=10mA			720	mV
f_T	Current Gain Bandwidth Product	V_{CE}=5V, I_C=10mA, f=100MHz		300		MHz
C_{ob}	Output Capacitance	V_{CB}=10V, I_E=0, f=1MHz		3.5	6	pF
C_{ib}	Input Capacitance	V_{EB}=0.5V, I_C=0, f=1MHz		9		pF
NF	Noise Figure : BC546/547/548	V_{CE}=5V, I_C=200μA		2	10	dB
	: BC549/550	f=1KHz, R_G=2KΩ		1.2	4	dB
	: BC549	V_{CE}=5V, I_C=200μA		1.4	4	dB
	: BC550	R_G=2KΩ, f=30~15000MHz		1.4	3	dB

h_{FE} Classification

Classification	A	B	C
h_{FE}	110 ~ 220	200 ~ 450	420 ~ 800

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Typical Characteristics

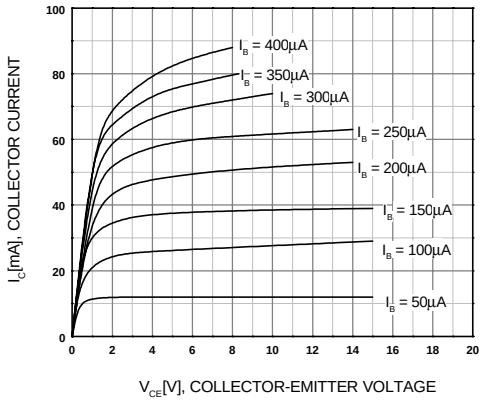

Figure 1. Static Characteristic

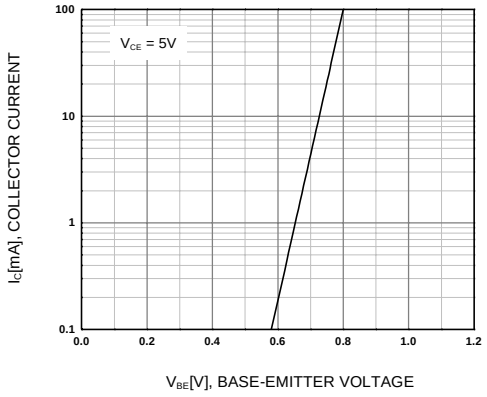

Figure 2. Transfer Characteristic

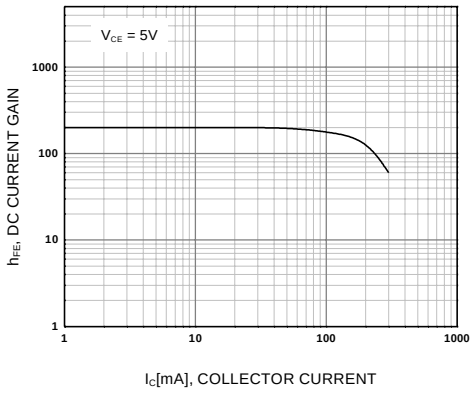

Figure 3. DC current Gain

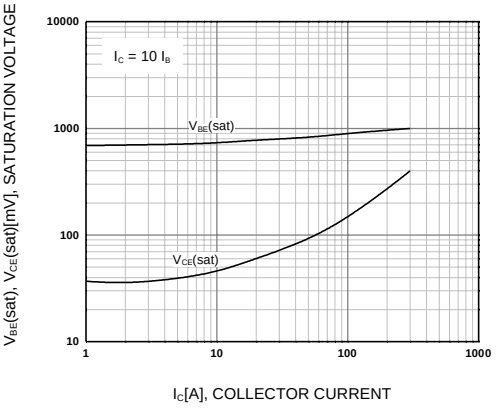

Figure 4. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

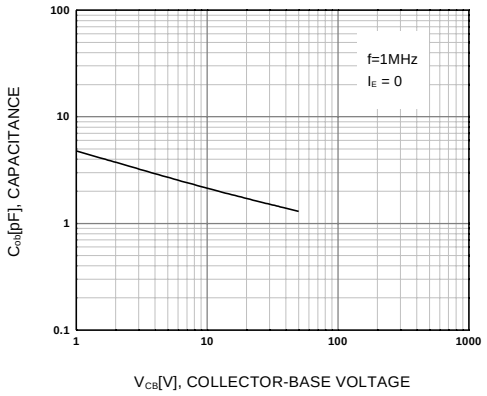

Figure 5. Output Capacitance

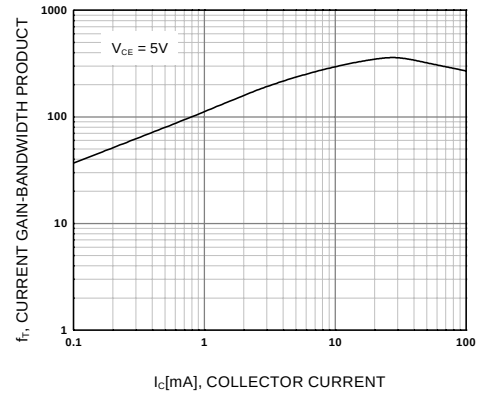

Figure 6. Current Gain Bandwidth Product

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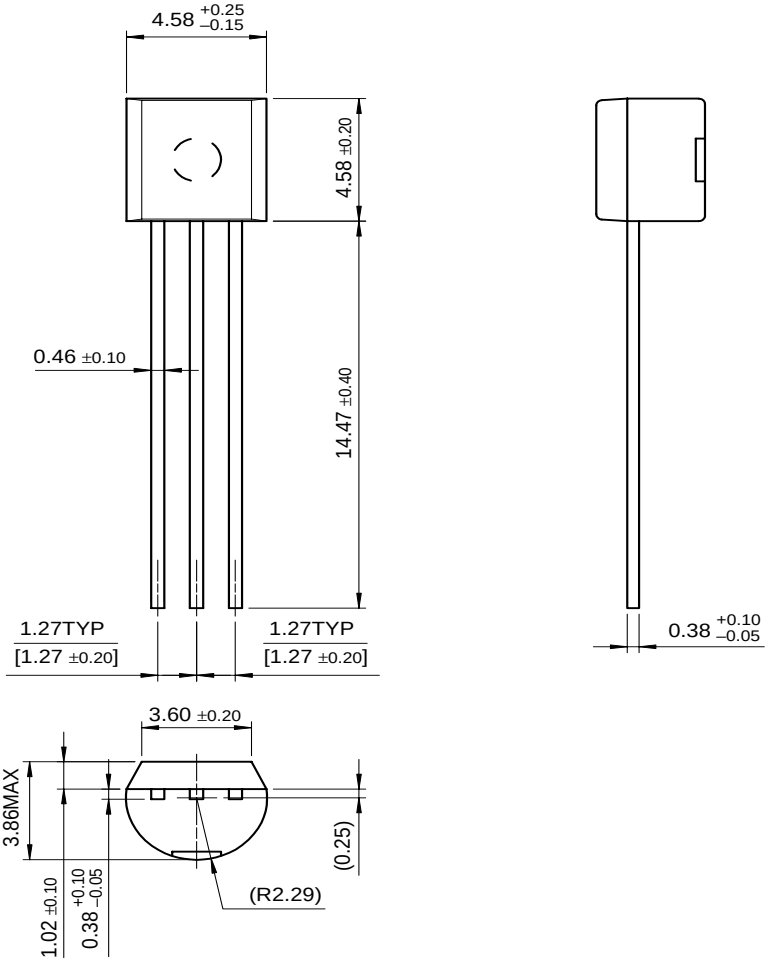
Package Dimensions

TO-92



Dimensions in Millimeters

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CoolFET™	FASTr™	MicroFET™	PowerTrench®	SuperSOT™-6
CROSSVOLT™	FRFET™	MicroPak™	QFET™	SuperSOT™-8
DOME™	GlobalOptoisolator™	MICROWIRE™	QS™	SyncFET™
EcoSPARK™	GTO™	MSX™	QT Optoelectronics™	TinyLogic™
E^2CMOS™	HiSeC™	MSXPro™	Quiet Series™	TruTranslation™
EnSigna™	I^2C™	OCX™	RapidConfigure™	UHC™
Across the board. Around the world.™		OCXPro™	RapidConnect™	UltraFET®
The Power Franchise™		OPTOLOGIC®	SILENT SWITCHER®	VCX™
Programmable Active Droop™		OPTOPLANAR™	SMART START™	

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